Semiconductor Device Set - Page 1 of 1



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| Inclosure N     | Naterial:   |
|-----------------|---|
| Metal all tra   | nsistor   |
| Overall Ler     | ngth:   |
| 0.190 inche     | s all transistor  |
| Terminal Lo     | ength:  |
| 1.500 inche     | s all transistor  |
| Overall Dia     | meter:  |
| 0.209 inche     | s all transistor  |
| Internal Co     | nfiguration:  |
| Junction cor    | ntact all transistor  |
| Internal Jui    | nction Configuration:   |
| Pnp all trans   | sistor  |
| Componen        | t Function Relationship:  |
| Matched         |   |
| Componen        | t Name And Quantity:  |
| 2 transistor    |   |
| Mounting M      | Nethod:   |
| Terminal all    | transistor  |
| Terminal C      | ircle Diameter:   |
| 0.100 inche     | s all transistor  |
| Semicondu       | ictor Material:   |
| Silicon all tra | ansistor  |
| Voltage Ra      | ting In Volts Per Characteristic:   |
| 25.0 emitte     | r to base voltage, dc all transistor and 30.0 collector to base voltage, dc all transisto |
| Current Ra      | ting Per Characteristic:  |
| 10.00 milliai   | mperes source cutoff current all transistor   |
| Special Fea     | atures:   |
| Double emit     | tter  |
| Terminal Ty     | ype And Quantity:   |
| 4 uninsulate    | ed wire lead all transistor   |
| Shelf Life:     |   |
| N/a             |   |
| Unit Of Mea     | asure:  |
|                 |   |
| Demilitariza    | ation:  |
| No              |   |
| Fiig:           |   |
| -               |   |